



500V PNP HIGH VOLTAGE TRANSISTOR IN SOT223

Features

- $BV_{CEO} > -500V$
- I_C = -150mA High Continuous Current
- I_{CM} = -500mA Peak Pulse Current
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/
- An Automotive-Compliant Part is Available Under Separate Datasheet (FZT560Q)

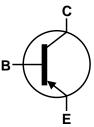
Mechanical Data

- Package: SOT223
- Package Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.112 grams (Approximate)

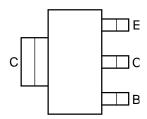








Device Symbol



Top View Pin-Out

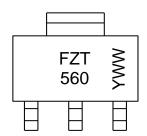
Ordering Information (Note 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FZT560TA	Standard	FZT560	7	12	1,000
FZT560TC	Standard	FZT560	13	12	4,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



FZT 560 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 2 = 2022) WW or $\overline{W}W = Week Code (01~53)$



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-500	V
Collector-Emitter Voltage	V_{CEO}	-500	V
Emitter-Base Voltage	V_{EBO}	-7	V
Continuous Collector Current	Ic	-150	mA
Peak Pulse Current	I _{CM}	-500	mA

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Davier Discipation	(Note 5)	D	2	W
Power Dissipation	(Note 6)	P _D	3	W
The second Designation and London Architecture	(Note 5)	D	62.5	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	41.7	°C/W
Thermal Resistance, Junction to Leads (Note 7)		$R_{ heta JL}$	14.8	°C/W
Operating and Storage Temperature Range	$T_{J_i}T_{STG}$	-55 to +150	°C	

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

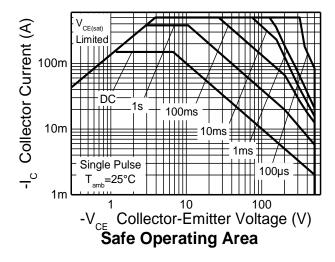
- 5. For a device mounted with the collector lead on 25mm x 25mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.
- Same as Note 5, except the device is mounted on 50mm x 50mm 2oz copper.
 Thermal resistance from junction to solder-point (at the end of the collector lead).
- 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

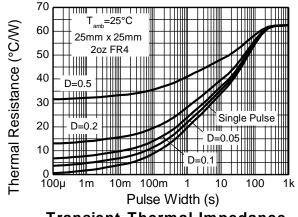
March 2022

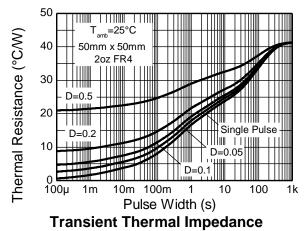
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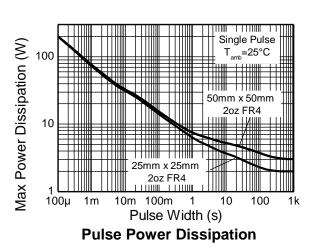
Thermal Characteristics and Derating Information

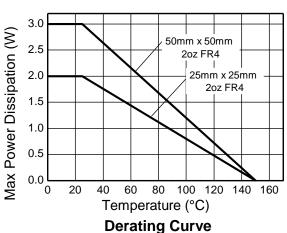






Transient Thermal Impedance







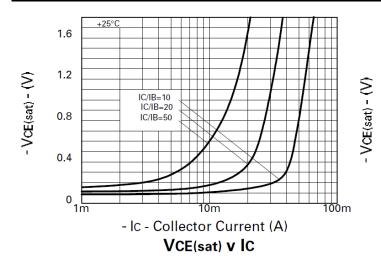
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

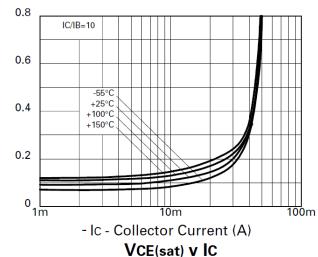
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_CBO	-500	_	-	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-500	_	-	V	$I_C = -1mA$
Emitter-Base Breakdown Voltage	BV_EBO	-7	_	-	V	I _E = -100μA
Collector Cut-Off Current	I _{CBO}	-	_	-100	nA	V _{CB} = -500V
Collector Cut-Off Current	I _{CES}	-	_	-100	nA	V _{CE} = -500V
Emitter Cut-Off Current	I _{EBO}	_	_	-100	nA	V _{EB} = -5.6V
Oallantes Fasition Oaksmation Value on (Nate O)	V _{CE(sat)}	_	_	-200	mV	$I_C = -20 \text{mA}, I_B = -2 \text{mA}$
Collector-Emitter Saturation Voltage (Note 9)		-	_	-500		$I_C = -50 \text{mA}, I_B = -10 \text{mA}$
Base-Emitter Saturation Voltage (Note 9)	$V_{BE(sat)}$	-	_	-900	mV	$I_C = -50 \text{mA}, I_B = -10 \text{mA}$
Base-Emitter Turn-On Voltage (Note 9)	$V_{BE(on)}$	_	_	-900	mV	$I_C = -50 \text{mA}, V_{CE} = -10 \text{V}$
	h _{FE}	100	_	300		$I_C = -1mA, V_{CE} = -10V$
DC Current Gain (Note 9)		80	_	300	_	$I_C = -50 \text{mA}, V_{CE} = -10 \text{V}$
, , ,		_	15	_		I _C = -100mA, V _{CE} = -10V
Current Gain-Bandwidth Product	fT	60			MHz	$V_{CE} = -20V, I_{C} = -10mA$
Current Gain-Bandwidth Product		60	_			f = 50MHz
Turn-On Time	t _{on}	-	110	_	ns	$V_{CC} = -100V, I_{C} = -50mA$
Turn-Off Time	t _{off}	_	1.5	-	μs	$I_{B1} = -5mA$, $I_{B2} = 10mA$
Output Capacitance	C_obo	_	_	8	pF	V _{CB} = -20V, f = 1MHz

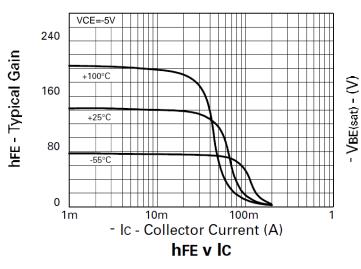
Note: 9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

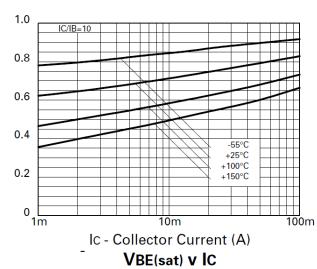


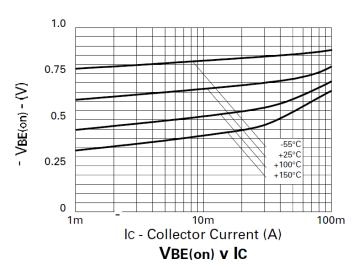
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)







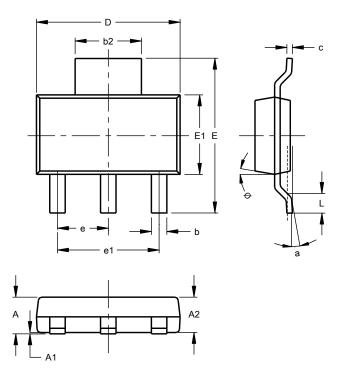






Package Outline Dimensions

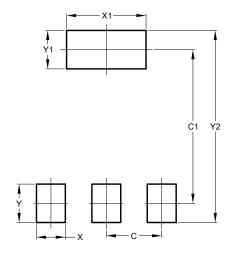
Please see https://www.diodes.com/design/support/packaging/diodes-packaging/ for the latest version.



SOT223 (Type ZN)					
Dim	Min	Max	Тур		
Α		1.70			
A1	0.02	0.10			
A2	1.50	1.68	1.60		
b	0.60	0.80			
b2	2.90	3.10			
С	0.24	0.32			
D	6.30	6.70			
Е	6.70	7.30			
E1	3.30	3.70			
е	2.30 NOM				
e1	4.60 NOM				
L	0.90				
а			10°		
Θ		15°			
All Dimensions in mm					

Suggested Pad Layout

Please see https://www.diodes.com/design/support/packaging/diodes-packaging/ for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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